



30V Dual P-Channel Enhancement Mode MOSFET

Voltage

-30 V

Current

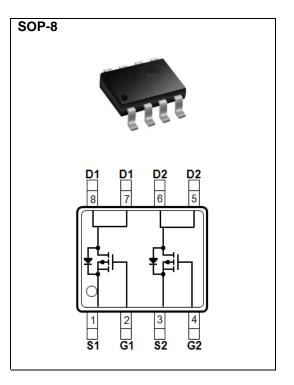
-5.3 A

Features

- R_{DS(ON)}, V_{GS}@-10V, I_D@-4A<30mΩ
- $\bullet~R_{DS(ON)}$, $V_{GS}@\text{-}4.5V,~I_{D}@\text{-}2A\text{<}45m\Omega$
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS2.0 (2011/65/EU & 2015/865/EU directive)
- Green molding compound as per IEC61249 Std.. (Halogen Free)

Mechanical Data

- Case: SOP-8 package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0029 ounces, 0.083 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	-30	V	
Gate-Source Voltage		V_{GS}	<u>+</u> 20	V	
Continuous Drain Current	T _A =25°C		-5.3		
	T _A =70°C	I _D	-4.2	Α	
Pulsed Drain Current (Note 1)		I _{DM}	-24		
Power Dissipation	T _A =25°C		1.25	W	
	T _A =70°C	P_{D}	0.8		
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55~150	°C	
Typical Thermal Resistance					
- Junction to Ambient (Note 5)		$R_{\theta JA}$	100	°C/W	





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS		
Static								
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V,I _D =-250uA V _{DS} =V _{GS} ,I _D =-250uA	-30	-	-	V		
Gate Threshold Voltage	$V_{GS(th)}$		-1.0	-1.6	-2.5			
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-10V,I _D =-4A	-	26	30	mΩ		
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-4.5V,I _D =-2A	-	36	45			
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =-30V, V_{GS} =0V	-	-	-1.0	uA		
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 20V,V _{DS} =0V	-	-	<u>+</u> 100	nA		
Dynamic (Note 6)								
Total Gate Charge	Q_g	V _{DS} =-15V, I _D =-5A, V _{GS} =-4.5V (Note 1,2)	-	7.8	-	nC		
Gate-Source Charge	Q_gs		-	2.7	-			
Gate-Drain Charge	Q_{gd}		-	2.8	-			
Input Capacitance	Ciss	V _{DS} =-15V, V _{GS} =0V, f=1.0MHZ	-	870	-	pF		
Output Capacitance	Coss		-	130	-			
Reverse Transfer Capacitance	Crss	1-1.0IVII IZ	-	93	-			
Turn-On Delay Time	td _(on)	\/ 45\/\D 44	-	6.5	-			
Turn-On Rise Time	tr	V_{DS} =-15V,ID=-1A, V_{GS} =-10V, R _G =6 Ω	-	8.8	-	ns		
Turn-Off Delay Time	td _(off)	V _{GS} =-10V, R _G =012 (Note 1,2)	-	73	-			
Turn-Off Fall Time	tf		-	44	-			
Drain-Source Diode								
Maximum Continuous Drain-Source	l.		_	_	-5.3	A		
Diode Forward Current	I _S		_		-0.0	^		
Diode Forward Voltage	V_{SD}	I _S =-1A, V _{GS} =0V	-	-0.75	-1.0	V		

NOTES:

- 1. Pulse width<300us, Duty cycle<2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. The maximum current rating is package limited.
- 4. Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}$ =150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
- 5. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

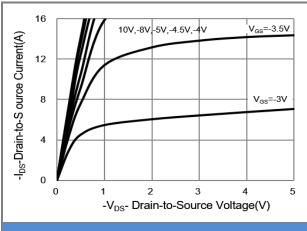


Fig.1 On-Region Characteristics

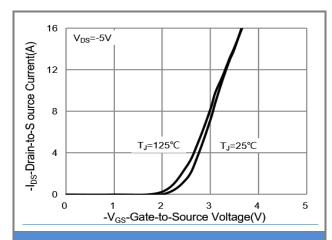


Fig.2 Transfer Characteristics

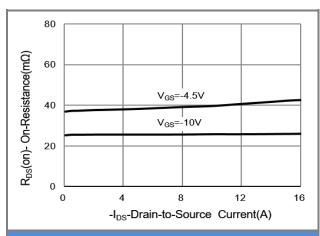


Fig.3 On-Resistance vs. Drain Current

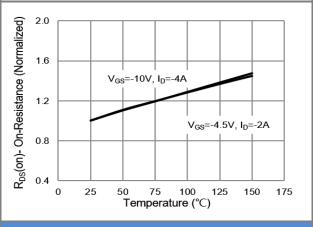
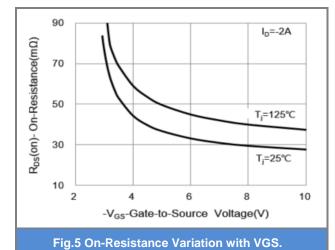


Fig.4 On-Resistance vs. Junction temperature



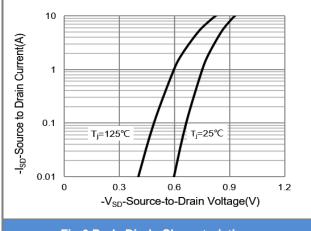


Fig.6 Body Diode Characteristics





TYPICAL CHARACTERISTIC CURVES

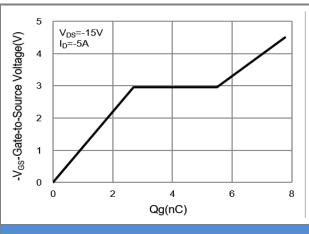
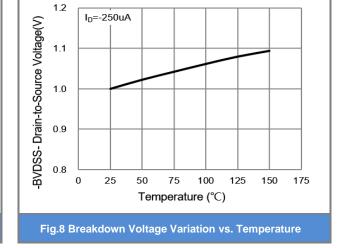


Fig.7 Gate-Charge Characteristics



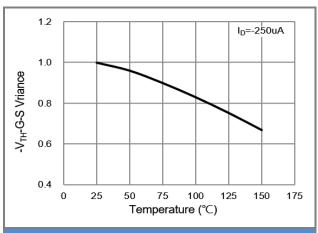


Fig.9 Threshold Voltage Variation with Temperature.

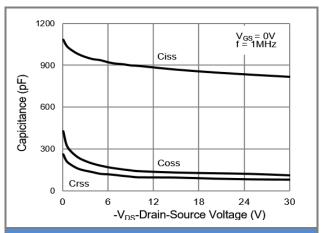


Fig.10 Capacitance vs. Drain-Source Voltage.

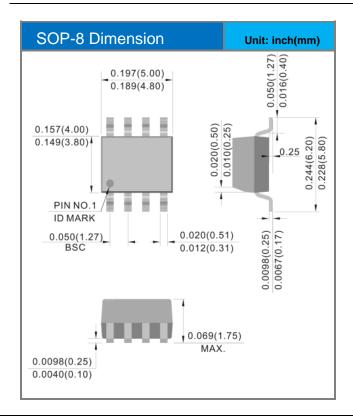


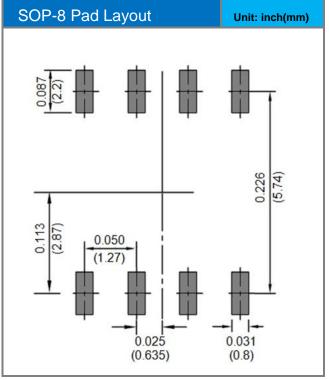


Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJL9809_R2_00001	SOP-8	2.5K pcs / 13" reel	L9809	Halogen free

Packaging Information & Mounting Pad Layout









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